

Example: LED Output Wavelength Variation

- Consider a GaAs LED
- GaAs bandgap at 300K is 1.42 eV
- Derivative of the bandgap is

$$\frac{dE_g}{dT} = -4.5 \times 10^{-4} \frac{eV}{K}$$

- What is the change in emitted wavelength if the temperature is 10°C?

$$E_g = \frac{hc}{e\lambda} - \frac{k_B T}{e}$$

$$\lambda = \frac{c}{\nu} = \frac{hc}{E_g} = \frac{(6.626 \times 10^{-34})(3 \times 10^8)}{(1.42 \times 1.6 \times 10^{-19})} = \frac{1.24 \times 10^{-6} eV * m}{1.42 eV} = 875 nm$$

$$\frac{d\lambda}{dT} = -\frac{hc}{E_g^2} \left(\frac{dE_g}{dT} \right) = -\frac{(6.626 \times 10^{-34})(3 \times 10^8)}{(1.42 \times 1.6 \times 10^{-19})^2} (-4.5 \times 10^{-4})(1.6 \times 10^{-19}) \frac{m}{K}$$

$$\frac{d\lambda}{dT} \approx 2.77 \times 10^{-10} \frac{m}{K} = 0.277 \frac{nm}{K}$$

$$\Delta\lambda = \frac{d\lambda}{dT} \Delta T \approx 0.277 \frac{nm}{K} \times 10K \approx 2.8 nm$$

- Since E_g decreases with temperature, the wavelength increases with temperature. This calculated change is within 10% of typical values for GaAs LEDs quoted in the literature

Example: InGaAsP on InP Substrate

- Ternary alloy $\text{In}_{1-x}\text{Ga}_x\text{As}_y\text{P}_{1-y}$ is grown on an InP crystal substrate for LED applications
- The device requires sufficiently small lattice strain due to mismatch between the two crystals at the interface to allow for electroluminescence.
- Strain reduction in tern requires a value for $y = 2.2x$
- The bandgap energy for the alloy in eV is given by the empirical relationship

$$E_g \approx 1.35 - 0.72y + 1.12y^2$$

$$0 \leq x \leq 0.47$$

- Calculate the composition of InGaAsP ternary alloys for peak emission at a wavelength of 1.3 um

$$E_g = \frac{hc}{e\lambda} - \frac{k_B T}{e} \quad \text{For} \quad \lambda = 1300\text{nm}; T = 300K$$

$$E_g = \frac{hc}{e\lambda} - \frac{k_B T}{e} = \frac{(6.626 \times 10^{-34})(3 \times 10^8)}{(1.6 \times 10^{-19})(1.3 \times 10^{-6})} - 0.0259\text{eV} = 0.928\text{eV}$$

$$E_g = 0.928 = 1.35 - 0.72y + 1.12y^2$$

$$y = 0.66$$

$$x = 0.66 / 2.2 = 0.3$$

- Requires $\text{In}_{0.7}\text{Ga}_{0.3}\text{As}_{0.66}\text{P}_{0.34}$